NSN 5961-01-094-3749

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Inclosure Material:

Metal

Overall Length:

0.050 inches

Overall Height:

0.410 inches

Overall Width:

0.330 inches

Function For Which Designed:

Microwave

End Application:

An/fps-115/120

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 collector to base voltage, dc and 20.0 collector to emitter voltage, dc and 1.0 emitter to base voltage, dc

Current Rating Per Characteristic:

100.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Test Data Document:

49956-914592 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0